

1.本站收集的数据手册和产品资料都来自互联网,版权归原作者所有。如读者和版权方有任 何异议请及时告之,我们将妥善解决。

本站提供的中文数据手册是英文数据手册的中文翻译,其目的是协助用户阅读,该译文无法自动跟随原稿更新,同时也可能存在翻译上的不当。建议读者以英文原稿为参考以便获得更精准的信息。

3.本站提供的产品资料,来自厂商的技术支持或者使用者的心得体会等,其内容可能存在描 叙上的差异,建议读者做出适当判断。

4.如需与我们联系,请发邮件到marketing@iczoom.com,主题请标有"数据手册"字样。

Read Statement

1. The datasheets and other product information on the site are all from network reference or other public materials, and the copyright belongs to the original author and original published source. If readers and copyright owners have any objections, please contact us and we will deal with it in a timely manner.

2. The Chinese datasheets provided on the website is a Chinese translation of the English datasheets. Its purpose is for reader's learning exchange only and do not involve commercial purposes. The translation cannot be automatically updated with the original manuscript, and there may also be improper translations. Readers are advised to use the English manuscript as a reference for more accurate information.

3. All product information provided on the website refer to solutions from manufacturers' technical support or users the contents may have differences in description, and readers are advised to take the original article as the standard.

4. If you have any questions, please contact us at marketing@iczoom.com and mark the subject with "Datasheets".

ON Semiconductor[®]



ASM3P2779A

Peak EMI Reducing Solution

Features

- Generates an EMI optimized clock signal at the output.
- Integrated loop filter components.
- Operates with a 3.3 / 2.5V Supply.
- Operating current less than 4mA.
- CMOS design.
- Input frequency range: 13MHz to 30MHz for 2.5V 13MHz to 30MHz for 3.3V
- Generates a 1X low EMI spread spectrum clock of the input frequency.
- Frequency deviation: ±1% (Typ) @ 16MHz Input Frequency.
- Available in 6L-TSOP (6L-TSOT-23).

Product Description

The ASM3P2779A is a versatile spread spectrum frequency modulator designed specifically for a wide range of clock frequencies. The ASM3P2779A reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of all clock dependent signals. The ASM3P2779A allows significant system cost savings by reducing the number of circuit board layers, ferrite beads and shielding that are traditionally required to pass EMI regulations.

The ASM3P2779A uses the most efficient and optimized modulation profile approved by the FCC and is implemented by using a proprietary all digital method.

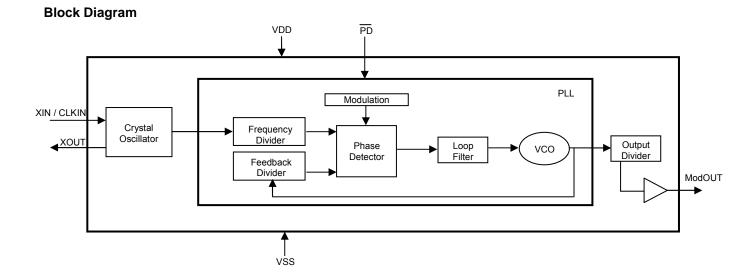
The ASM3P2779A modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation.'

Applications

The ASM3P2779A is targeted towards all portable devices like MP3 players and digital still cameras.

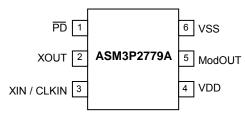
Key Specifications

| Description | Specification |
|--------------------------|-------------------------------|
| Supply voltages | V _{DD} = 3.3V / 2.5V |
| Cycle-to-Cycle Jitter | ±200pS (Typ) |
| Output Duty Cycle | 45/55% |
| Modulation Rate Equation | F _{IN} /640 |
| Frequency Deviation | ±1% (Typ) @ 16MHz |



©2010 SCILLC. All rights reserved. OCTOBER 2010 - Rev. 4.1

Pin Configuration (6L-TSOP Package)



Pin Description

| Pin# | Pin Name | Туре | Description | | | |
|------|-------------|------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|--|
| 1 | PD | I | Power-down control pin. Pull low to enable power-down mode. Connect to VDD if not used. | | | |
| 2 | XOUT | 0 | Crystal connection. If using an external reference, this pin must be left unconnected. | | | |
| 3 | XIN / CLKIN | I | Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or an external reference clock. | | | |
| 4 | VDD | Р | Power supply for the entire chip. | | | |
| 5 | ModOUT | 0 | Spread spectrum clock output. | | | |
| 6 | VSS | Р | Ground connection. | | | |

Specifications

| Desc | Description Specification | |
|---------------------|---------------------------|-----------------------|
| Frequency Range | For 2.5V Supply | 13MHz < CLKIN < 30MHz |
| | For 3.3V Supply | 13MHz < CLKIN < 30MHz |
| Modulation Equation | n | F _{IN} /640 |
| Frequency Deviation | n | ±1% (Typ) @ 16MHz |

Absolute Maximum Ratings

| Symbol | Parameter | Rating | Unit | | | | |
|-------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|------|--|--|--|--|
| VDD, V _{IN} | Voltage on any pin with respect to Ground | -0.5 to +4.6 | V | | | | |
| T _{STG} | Storage temperature | -65 to +125 | C | | | | |
| T _A | Operating temperature | 0 to +70 | C | | | | |
| Ts | Max. Soldering Temperature (10 sec) | 260 | C | | | | |
| TJ | Junction Temperature | 150 | C | | | | |
| T _{DV} Static Discharge Voltage 2 KV (As per JEDEC STD22- A114-B) | | | | | | | |
| | Note: These are stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect device reliability. | | | | | | |

Operating Conditions

| Parameter | Description | Min | Max | Unit |
|-----------------|---------------------------------------------|-------|-----|------|
| VDD | Supply Voltage | 2.375 | 3.6 | V |
| TA | Operating Temperature (Ambient Temperature) | -40 | +85 | C |
| CL | Load Capacitance | | 15 | pF |
| C _{IN} | Input Capacitance | | 7 | pF |

| Symbol | Parameter | Min | Тур | Max | Unit |
|------------------|--------------------------------------------------------------------------------------------------------------------|---------|-----|---------|------|
| VIL | Input low voltage | VSS-0.3 | | 0.8 | V |
| V _{IH} | Input high voltage | 2.0 | | VDD+0.3 | V |
| I _{IL} | Input low current | | | -35 | μA |
| I _{IH} | Input high current | | | 35 | μA |
| I _{XOL} | XOUT output low current (@ 0.5V, VDD = 2.5V) | | 3 | | mA |
| I _{XOH} | XOUT output high current (@ 1.8V, VDD = 2.5V) | | 3 | | mA |
| V _{OL} | Output low voltage (VDD = 2.5 V, I _{OL} = 8mA) | | | 0.6 | V |
| V _{OH} | Output high voltage (VDD = 2.5 V, I_{OH} = 8mA) | 1.8 | | | V |
| I _{DD} | Static supply current ¹ | | | 2.0 | uA |
| Icc | Dynamic supply current (2.5V, 16MHz and no load) | | 3.0 | | mA |
| VDD | Operating Voltage | 2.375 | 2.5 | 2.625 | V |
| t _{ON} | Power-up time (first locked cycle after power-up) ² | | | 5 | mS |
| Zout | Output impedance | | 50 | | Ω |
| | / CLKIN pin and PD pin are pulle <u>d lo</u> w. and XIN / CLKIN input are stable, PD pin is made high from low. | | | | |

DC Electrical Characteristics for 2.5V Supply

AC Electrical Characteristics for 2.5V Supply

| Symbol | Parameter | | | Тур | Max | Unit |
|----------------------------------------------------|------------------------------------------|-----------------------------------------------|------|-------|-----|------|
| CLKIN | Input frequency | | 13 | | 30 | MHz |
| ModOUT | Output frequency | | 13 | | 30 | MHz |
| f _d | Frequency Deviation | Input Frequency = 13MHz | | ±1.15 | | % |
| Id | Input Frequency = 30MHz | | ±0.6 | | 70 | |
| t _{LH} 1 | Output rise time (measured fr | Output rise time (measured from 0.7V to 1.7V) | | 1.4 | 1.8 | nS |
| t _{HL} ¹ | Output fall time (measured fro | Output fall time (measured from 1.7V to 0.7V) | | 0.9 | 1.1 | nS |
| t _{JC} | Jitter (cycle-to-cycle) | | | ±200 | | pS |
| t _D | Output duty cycle | | 45 | 50 | 55 | % |
| Note: 1. t_{LH} and t_{HL} are m | neasured into a capacitive load of 15pF. | | | | | |

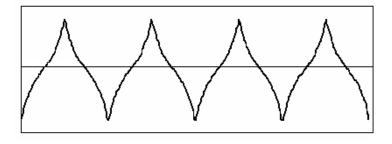
| Symbol | Parameter | Min | Тур | Мах | Unit |
|------------------|-----------------------------------------------------------------------------------------------------------|---------|-----|---------|------|
| VIL | Input low voltage | VSS-0.3 | | 0.8 | V |
| V _{IH} | Input high voltage | 2.0 | | VDD+0.3 | V |
| IIL | Input low current | | | -35 | μA |
| I _{IH} | Input high current | | | 35 | μA |
| I _{XOL} | XOUT output low current (@ 0.4V, VDD = 3.3V) | | 3 | | mA |
| I _{XOH} | XOUT output high current (@ 2.5V, VDD = 3.3V) | | 3 | | mA |
| V _{OL} | Output low voltage (VDD = 3.3 V, I _{OL} = 8mA) | | | 0.4 | V |
| V _{OH} | Output high voltage (VDD = 3.3 V, I _{OH} = 8mA) | 2.5 | | | V |
| I _{DD} | Static supply current ¹ | | | 2.0 | uA |
| Icc | Dynamic supply current (3.3V, 16MHz and no load) | | 3.5 | | mA |
| VDD | Operating Voltage | 2.7 | 3.3 | 3.6 | V |
| t _{ON} | Power-up time (first locked cycle after power-up) ² | | | 5 | mS |
| Z _{OUT} | DUT Output impedance 45 Ω | | | | |
| | / CLKIN pin and PD pin are pulled low. and XIN / CLKIN input are stable, PD pin is made high from low. | | • | | |

DC Electrical Characteristics for 3.3V Supply

AC Electrical Characteristics for 3.3V Supply

| Symbol | Parameter | | | Тур | Max | Unit |
|---------------------------------------|-------------------------------------------------------------------------------------------|----------------------------------------------|----|-------|-----|------|
| CLKIN | Input frequency | | 13 | | 30 | MHz |
| ModOUT | Output frequency | | 13 | v | 30 | MHz |
| fd | Frequency Deviation | Input Frequency = 13MHz | | ±1.15 | | % |
| Id | Trequency Deviation | Input Frequency = 30MHz | | ±0.6 | | 70 |
| t _{LH} 1 | Output rise time (measur | Output rise time (measured from 0.8 to 2.0V) | | 1.1 | 1.3 | nS |
| t _{HL} 1 | Output fall time (measure | Output fall time (measured at 2.0V to 0.8V) | | 0.8 | 0.9 | nS |
| t _{JC} | Jitter (cycle-to-cycle) | Jitter (cycle-to-cycle) | | ±200 | | pS |
| t _D | Output duty cycle | | 45 | 50 | 55 | % |
| Note: 1. t_{LH} and t_{HL} are me | lote: 1. t _{LH} and t _{HL} are measured into a capacitive load of 15pF. | | | | | |

Modulation Profile

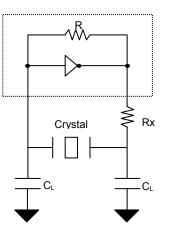


Typical Crystal Specifications

| Fundamental AT cut parallel resonant crystal | | | | |
|----------------------------------------------|---------------------------|--|--|--|
| Nominal frequency | 16MHz | | | |
| Frequency tolerance | ± 50 ppm or better at 25℃ | | | |
| Operating temperature range | -25℃ to +85℃ | | | |
| Storage temperature | -40℃ to +85℃ | | | |
| Load capacitance(C _P) | 18pF | | | |
| Shunt capacitance | 7pF maximum | | | |
| ESR | 25 Ω | | | |

Note: Note: CL is Load Capacitance and Rx is used to prevent oscillations at overtone frequency of the Fundamental frequency.

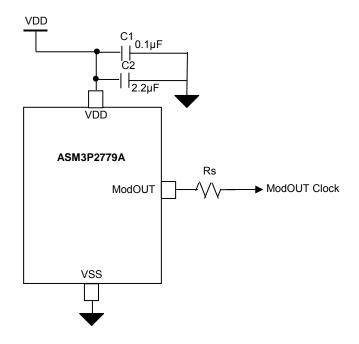
Typical Crystal Interface Circuit



 $C_L = 2^* (C_P - C_S), \\ \text{Where } C_P = \text{Load capacitance of crystal}$

 C_{S} = Stray capacitance due to C_{IN} , PCB, Trace etc.

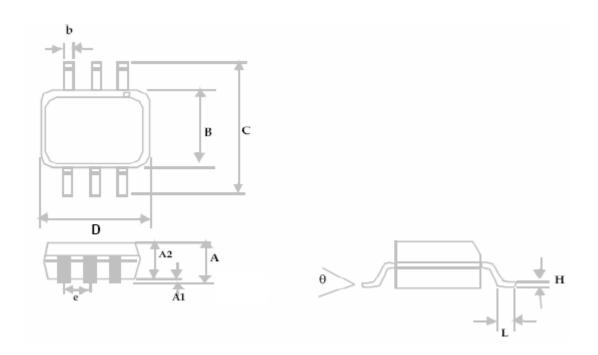
Typical Application Schematic



ASM3P2779A

Package Information





| | Dimensions | | | | |
|--------|------------|-------|-------------|------|--|
| Symbol | Inc | hes | Millimeters | | |
| | Min | Max | Min | Max | |
| А | | 0.04 | | 1.00 | |
| A1 | 0.00 | 0.004 | 0.00 | 0.10 | |
| A2 | 0.033 | 0.036 | 0.84 | 0.90 | |
| b | 0.012 | 0.02 | 0.30 | 0.50 | |
| Н | 0.005 | BSC | 0.127 | BSC | |
| D | 0.114 | BSC | 2.90 | BSC | |
| В | 0.06 | BSC | 1.60 | BSC | |
| е | 0.037 | 4 BSC | 0.950 | BSC | |
| С | 0.11 BSC | | 2.80 | BSC | |
| L | 0.0118 | 0.02 | 0.30 | 0.50 | |
| θ | 0° | 4° | 0° | 4° | |

ASM3P2779A

Ordering Information

| Part Number Marking | | Package Type | Temperature |
|---------------------|-----|-----------------------------------------------|--------------|
| ASM3P2779AF-06OR | A4L | 6L-TSOP(6L-TSOT-23)., TAPE & REEL, Pb Free | 0℃ to +70℃ |
| ASM312779AF-06OR | A5L | 6L-TSOP(6L-TSOT-23)., TAPE & REEL, Pb Free | -40℃ to +85℃ |

A "microdot" placed at the end of last row of marking or just below the last row toward the center of package indicates Pb-free.

ON Semiconductor and ^(IIII) are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. U.S Patent Pending; Timing-Safe and Active Bead are trademarks of PulseCore Semiconductor, a wholly owned subsidiary of ON Semiconductor. This literature is subject to all applicable cop

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA **Phone:** 303-675-2175 or 800-344-3860 Toll Free USA/Canada **Fax:** 303-675-2176 or 800-344-3867 Toll Free USA/Canada **Email:** orderlit@onsemi.com N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative